NSN 5961-01-021-5632

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-021-5632 **Inclosure Material:** Metal **Overall Length:** 0.187 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 6 semiconductor device diode **Mounting Method: Terminal Terminal Circle Diameter:** 0.245 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 5.0 reverse voltage, peak 5th semiconductor device diode **Current Rating Per Characteristic:** 25.00 milliamperes source cutoff current preset all semiconductor device diode **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 12 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No